

High-performance MEMS microphone with extended frequency response up to 80 kHz for ultrasound applications



RHLGA metal cap 5-lead 3.5 x 2.65 x 0.98 mm

Features

- Single supply voltage operation 1.52 V 3.6 V
- Omnidirectional sensitivity
- · High signal-to-noise ratio
- High acoustic overload point: 130 dBSPL typ.
- · Package compliant with reflow soldering
- Enhanced RF immunity
- · Ultra-flat frequency response
- Ultrasound bandwidth (up to 80 kHz)
- Low latency
- Ultra-low-power: 150 μA max.
- · ECOPACK, RoHS, and "Green" compliant

Applications

- · Condition monitoring of industrial equipment
- Leak detection
- · Electrical arcing
- · Smart medical instruments
- · Wearable devices
- Hearables
- Smart speakers
- Active noise-canceling headsets

Product status link

IMP23ABSU

Product summary			
Order code	IMP23ABSUTR		
Temp. range [°C]	-40 to +85		
Package	(3.5 x 2.65 x 0.98) mm		
Packing	Tray Tape and reel		



Description

The IMP23ABSU is a compact, low-power microphone built with a capacitive sensing element and an IC interface.

The sensing element, capable of detecting acoustic waves, is manufactured using a specialized silicon micromachining process to produce audio sensors.

The IMP23ABSU has an acoustic overload point of 130 dBSPL with a typical 64 dB signal-to-noise ratio.

The sensitivity of the IMP23ABSU is -38 dBV ±1 dB @ 94 dBSPL, 1 kHz.

The IMP23ABSU is available in a package compliant with reflow soldering and is guaranteed to operate over an extended temperature range from -40 $^{\circ}$ C to +85 $^{\circ}$ C.



1 Pin description

5 1 4 2

Figure 1. Pin connections (bottom view)

Table 1. Pin description

Pin number	Pin name	Function
1	Out	Output
2	GND	GND
3	GND	GND
4	GND	GND
5	Vdd	Supply voltage

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2 Acoustic and electrical specifications

2.1 Acoustic and electrical characteristics

The values listed in the table below are specified for Vdd = 2.75 V, no load, Tamb = 25 °C unless otherwise specified.

Table 2. Acoustic and electrical characteristics

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vdd	Supply voltage		1.52	2.75	3.6	V
ldd	Current consumption			120	150	μA
So	Sensitivity	1 kHz @ 94 dBSPL	-39	-38	-37	dBV
SNR	Signal-to-noise ratio			64		dB(A)
PSRR	Power supply rejection	100 mVpp sine wave, 1 kHz, Vdd > 1.6 V		60		dB
AOP	Acoustic overload point			130		dBSPL
Rload	Load resistance ⁽¹⁾		15			kΩ
Тор	Operating temperature range		-40		+85	°C

^{1.} Guaranteed by design

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2.2 Frequency response

Figure 2. Typical free-field frequency response normalized at 1 kHz

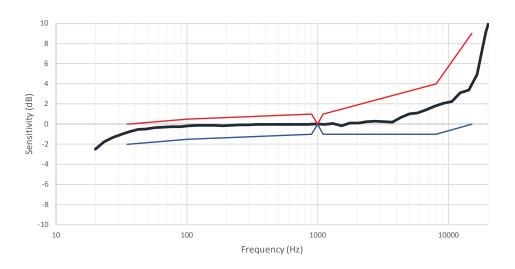
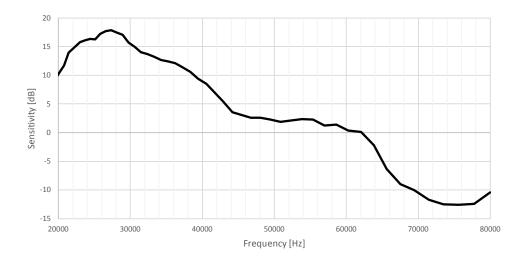


Table 3. Frequency response mask

Frequency (Hz)	LSL	USL	Unit
35	-2	0	dBr 1kHz
100	-1.5	0.5	dBr 1kHz
900	-1	1	dBr 1kHz
1000	0	0	dBr 1kHz
1100	-1	1	dBr 1kHz
8000	-1	4	dBr 1kHz
15000	0	9	dBr 1kHz

Figure 3. Typical ultrasonic free-field response normalized to 1 kHz



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3 Absolute maximum ratings

Stresses above those listed as "Absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device under these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 4. Absolute maximum ratings

Symbol	Ratings	Maximum value	Unit
Vdd	Supply voltage	-0.5 to 4.8	V
T _{STG}	Storage temperature range	-40 to +125	°C



This device is sensitive to mechanical shock, improper handling can cause permanent damage to the part.



This device is sensitive to electrostatic discharge (ESD), improper handling can cause permanent damage to the part.

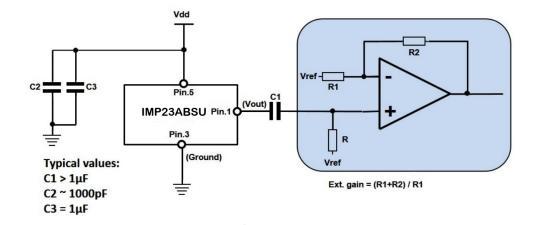
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4 Application recommendations

4.1 IMP23ABSU schematic hints

Figure 4. IMP23ABSU electrical connections and external component values



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5 Soldering information

T_P
T_L
T_{SMAX}
RAMP-UP
T_L
t_s
PREHEAT
RAMP-DOWN
T1D
T25°C to PEAK
TIME

Figure 5. Recommended soldering profile limits

Table 5. Recommended soldering profile limits

210

240

270

300

330

360 390

120 150 180

90

Description	Parameter	Pb free
Average ramp rate	T _L to T _P	3 °C/sec max
Preheat		
Minimum temperature	T _{SMIN}	150 °C
Maximum temperature	T _{SMAX}	200 °C
Time (T _{SMIN} to T _{SMAX})	t _S	60 sec to 120 sec
Ramp-up rate	T _{SMAX} to T _L	
Time maintained above liquidus temperature	t _L	60 sec to 150 sec
Liquidus temperature	TL	217 °C
Peak temperature	T _P	260 °C max
Time within 5 °C of actual peak temperature		20 sec to 40 sec
Ramp-down rate		6 °C/sec max
Time 25 °C (t25 °C) to peak temperature		8 minutes max

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6 Reliability tests

Table 6. Reliability specifications

Test name	Description	Conditions
		ESD-GUN: 25 discharges at ±8 kV, direct contact to housing of MIC
		Reference specification IEC 61000-4-2
		ESD-HBM 3 discharges up to ±2 kV pin-to-pin
Electrodatic Discharge leaves in Test	To classify ESD susceptibility the device is submitted to a high voltage peak on all his	Reference specification ANSI/ESDA/JEDEC JS001
Electrostatic Discharge Immunity Test (ESD)	pins, simulating ESD stress according to different simulation models (GUN, HBM, MM,	ESD-MM, 3 discharges up to ±200 V pin-to- pin
	CDM)	Reference specification JEDEC JESD22-A115C
		ESD-CDM, 3 discharges up to ±750 V
		Reference specification ANSI/ESDA/JEDEC JS002
Latch-Up	To verify latch-up immunity the device is	±100 mA & 1.5 x Vdd @ 85 °C
(LU)	submitted to a current injection on I/O or supply overvoltage	Reference specification JEDEC JESD78
High Temperature Operative Life	To simulate the worst-case application stress conditions, the device is stressed in dynamic	Ta 125 °C, Tj 125 °C, 1000 Hrs, @ Max Op Voltage
(HTOL)	configuration at operative max. absolute	Preconditioning (PC) before
	ratings	Reference specification JESD22-A108
Temperature Humidity Bias	To investigate failure mechanisms activated by electrical field and humidity, the device is	Ta 85°C, R.H. 85%, 1000 Hrs, @ Max Op Voltage
(THB)	biased in static or dynamic operative conditions at controlled high temperature and	Preconditioning (PC) before
	relative humidity	Reference specification JESD22-A101
Preconditioning MSL3 (PC)	To investigate effects of customer manufacturing soldering enhanced by package water absorption, the device is	MSL3 as moisture soak conditions followed by n.3 reflow @ Tpeak 260 °C
(- /	submitted to typical temperature profile after controlled moisture absorption	Reference specification JEDEC J-STD-020
	To investigate the failure mechanisms activated by extremely cold conditions, the	Ta = -40 °C, 1000 Hrs
Low Temperature Storage (LTS)	device is stored in unbiased condition at the min. temperature allowed by the package materials	Reference specification JESD22-A120
High Temperature Storage	To investigate the failure mechanisms activated by high temperature, the device is	Ta = 125 °C, 1000 Hrs
(HTS)	stored in unbiased condition at the maximum temperature allowed by the package materials	Reference specification JESD22-A104
Tomporature Cueling	To investigate failure modes related to thermo-mechanical stress, the device is	Low T = - 40 °C, High T = +125 °C, 1000 Cys
Temperature Cycling (TC)	submitted to cycled temperature excursions, between a hot and a cold chamber in air	Preconditioning (PC) before
	atmosphere	Reference specification JESD22-A105
Temperature Humidity Storage	To investigate degradations induced by wet	Ta = 85°C, R.H. = 85%, 1000Hrs
(THS)	conditions, the device is stored at controlled high temperature and relative humidity	Preconditioning (PC) before
	The state of the relative fluiding	Reference specification JESD22-A102

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Test name	Description	Conditions
Random Free-Fall on PCB (TUMBLE)	representation of processing and processing processing and process	
Guided Free-Fall on PCB (GFF)	To verify durability of the whole device to mechanical shocks, done by controlling height and impact direction simulating drop effect on handheld devices	Microphone soldered on PCB which is mounted on a specific jig Guided drop from 1.5 mt on marble base, 2 drops x 6 directions Reference specification IEC 60068-2-32
Compressed Air Test (CAT)	Test dedicated on the MEMS Microphone to check mechanical robustness of sensor membrane alone	Microphone membrane is subjected to repeated air pulses controlled on duration, rise and fall time and amplitude. Amplitude is varied with increasing steps. ST internal specification
Mechanical Shock (MS)	To verify mechanical robustness of internal structural elements (MEMS, package components) to withstand severe shocks produced by handling, transportation or field operations	Five pulses of 10,000 g in each of six directions with duration time 0.2 ms Reference specification MIL 883, Method 2002.5
Variable Frequency Vibration (VB)	The vibration variable frequency test is performed to determine the effect of vibration, within a specified frequency range, on the internal structural elements	Peak acceleration of 20 g, from 20 Hz to 2000 Hz in three perpendicular directions Reference specification MIL 883, Method 2007.3-A

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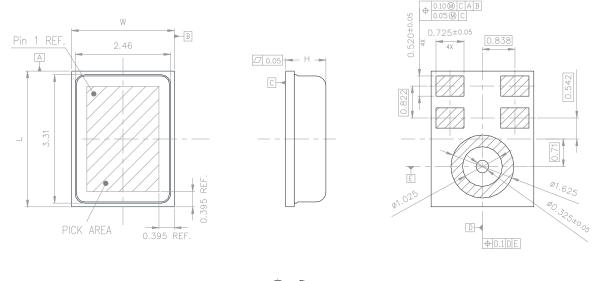


7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

7.1 RHLGA-5L package information

Figure 6. RHLGA metal cap 5-lead (3.5 x 2.65 x 0.98 mm) package outline and mechanical data





Dimensions are in millimeter unless otherwise specified General Tolerance is +/-0.15mm unless otherwise specified

OUTER DIMENSIONS

ITEM	DIMENSION [mm]	TOLERANCE [mm]
Length [L]	3.5	±0.1
Width [W]	2.65	±0.1
Height [H]	1.08 MAX	

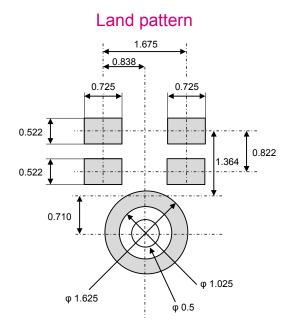
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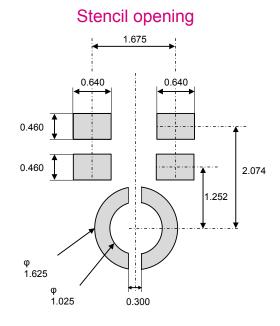
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7.2 Land pattern

Figure 7. Land pattern and recommended stencil opening



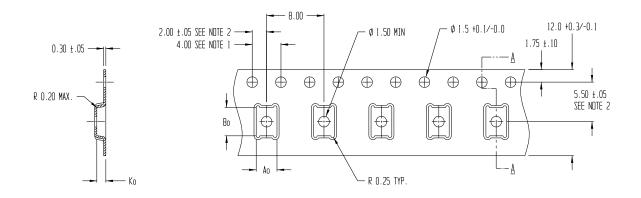


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RHLGA-5L packing information 7.3

Figure 8. Carrier tape information for RHLGA-5L package



SECTION A - A

Ao = 2.89Bo = 3.95 Ko = 1.25

1. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ±0.2

- 2. POCKET POSITION RELATIVE TO SPROCKET HOLE MEASURED
 AS TRUE POSITION OF POCKET, NOT POCKET HOLE
 3. AO AND BO ARE CALCULATED ON A PLANE AT A DISTANCE "R"
 ABOVE THE BOTTOM OF THE POCKET.

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Revision history

Table 7. Document revision history

Date	Version	Changes
31-Aug-2020	1	Initial release
16-Sep-2020	2	Minor textual update

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SPK0641HT4H-1 SPM0687LR5H-1 SPM1423HM4H-B SPQ1410HR5H-B SPU0410HR5H-PB